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--21. An electro-optical device of an active matrix comprising:
a gate line provided on a substrate;
a data line provided on said substrate;
an exclusive wiring provided on said substrate;
a pixel electrode provided on said substrate and superposed on said gate line with an insulator therebetween and superposed on said wiring with an insulator therebetween; and
at least one transistor provided on said substrate and connected with said gate line at a gate thereof and connected with said data line at one of source and drain thereof and connected with said pixel electrode at the other one of the source and drain.

22. An electro-optical device of an active matrix comprising:
a first gate line provided on a substrate;
a second gate line provided adjacent to said first gate line on said substrate;
a first pixel electrode provided on said substrate and connected with said first gate line through at least one first transistor; and
a second pixel electrode provided on said substrate and connected with said second gate line through at least one second transistor,
wherein said first pixel electrode is superposed on said first gate line with an insulator therebetween and is superposed on said second gate line with another insulator therebetween.

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23. An electro-optical device of an active matrix comprising:
a gate line provided on a substrate;